

Stimulated Emission of High-Frequency Phonons *

G. V. Kovalev

Engineering-Physics Institute, Moscow

(Dated: Apr. 24, 1978)

The motion of channeled particles is accompanied by the phonon emission. This feature can be used for the stimulated generation of phonons with large wave vectors and frequencies.

PACS numbers: 61.80.Fe

Difficulties are encountered [1] when the usual methods for the excitation of phonons are extended to large wave vectors $\mathbf{q} \approx 0.5 \cdot 10^5 \text{ cm}^{-1}$. For example, when such phonons are generated by the Raman scattering of laser light, it is necessary to use lasers emitting in the ultraviolet range. We shall consider the generation of phonons with $\mathbf{q} \approx \mathbf{K}$ ($\mathbf{K}$ is the reciprocal lattice vector) by a fast charged particle moving in a crystal under channeling conditions. The motion of channeled particles is known to be characterized by discrete transverse oscillations and free motion in the longitudinal direction. The interaction with thermal vibrations of the lattice facilitates transitions of a particle between discrete transverse levels accompanied by the emission of several phonons. If the gap between the levels $\Delta \epsilon_{nn'}$ is less than the Debye frequency w_D , the transition of a particle from a level n to a level n' characterized by conservation of the longitudinal momentum is accompanied mainly by one-phonon emission when the energy of new phonons ω_k is $\Delta \epsilon_{nn'}$ in the transverse direction. The value of $\Delta \epsilon_{nn'}$ may vary within wide limits with the energy of the particle. In the case of planar channeling of positrons in a parabolic potential [2] we have $\Delta \epsilon_{nn'} \approx 10\gamma^{-1/2} \text{ eV}$ [$\gamma = (1 - v^2)^{-1/2}$ is the relativistic factor and $\hbar = c = 1$].

The matrix element of a transition of a particle from an initial state $\Psi_i = \exp[i\mathbf{p}_{\parallel}\mathbf{r}_{\parallel}]u_n(x)$ to a final state $\Psi_f = \exp[i\mathbf{p}'_{\parallel}\mathbf{r}_{\parallel}]u_{n'}(x)$ accompanied by a transition of a crystal from a state Φ_{β} to a state $\Phi_{\beta'}$ is

$$M_{\beta'\beta}^{fi} = \langle \Phi_{\beta'} | \Psi_f | W | \Psi_i | \Phi_{\beta} \rangle, \quad (1)$$

where $W(\mathbf{r}, \{\mathbf{R}_j\})$ is the difference between the true potential $V(\mathbf{r}, \{\mathbf{R}_j\}) = \sum_{j,\mathbf{q}} V_{\mathbf{q}} \exp i\mathbf{q}(\mathbf{r} - \mathbf{R}_j^0 - \mathbf{u}_j)$ and the potential, averaged along the yOz plane, of atoms at rest at the equilibrium positions $\bar{U}(\mathbf{r}, \{\mathbf{R}_j^0\})$ [3]. For a purely inelastic process we have $\langle \Phi_{\beta'} | \bar{U} | \Phi_{\beta} \rangle = 0$, and, consequently, the nondiagonal terms $M_{\beta'\beta}^{fi}$ are governed only by the potential $V(\mathbf{r}, \{\mathbf{R}_j\})$. An explicit calculation of the matrix element (1) for the process involving s phonons gives

$$M_{\beta'\beta}^{fi} = \sum_{j,\mathbf{q}} e^{-Z_j/2} \delta_{\mathbf{p}_{\parallel} - \mathbf{p}'_{\parallel}, \mathbf{q}_{\parallel}} V_{\mathbf{q}} e^{-i\mathbf{R}_j^0(\mathbf{q} - \sum_{\alpha=1}^s \pm \mathbf{f}_{\alpha})} \times$$

$$\times \int u_{n'}^* u_n e^{iq_x x} dx \prod_{\alpha=1}^s (\mathbf{q}, \mathbf{e}_j(\beta_{\alpha})) \sqrt{\frac{n_{\beta_{\alpha}} + \frac{1}{2} \pm \frac{1}{2}}{2M_j n \omega(\beta_{\alpha})}}, \quad (2)$$

where

$$Z_j = \frac{1}{2M_j N} \sum_{\beta} \frac{(\mathbf{q}, \mathbf{e}_j(\beta))^2}{\omega(\beta)} (2n_{\beta} + 1),$$

and $\beta_{\alpha} = (\mathbf{f}_{\alpha}, \xi_{\alpha})$ is the combination of the wave vector with the branch number of a phonon α . The following laws of conservation of momentum and energy are satisfied:

$$\begin{aligned} \mathbf{p}_{\parallel} - \mathbf{p}'_{\parallel} &= \sum_{\alpha=1}^s \pm \mathbf{f}_{\parallel\alpha} + \mathbf{K}_{\parallel}, \\ E - E' &= \sum_{\alpha=1}^s \pm \omega_{\alpha}. \end{aligned} \quad (3)$$

We shall consider phonon generation in the case when a particle undergoes a transition from one level to another ($\Delta \epsilon_{nn'} \neq 0$, where $\Delta \epsilon_{nn} = 0$ corresponds to the usual Cherenkov phonon emission). In the relativistic case it is found from Eq. (3) that

$$\sum_{\alpha=1}^s \pm \omega_{\alpha} \cong \Delta \epsilon_{nn'} + \sum_{\alpha=1}^s \pm f_{\parallel\alpha} + K_{\parallel}. \quad (4)$$

In the scattering process accompanied by the emission of one phonon we can confine our attention to the $K_{\parallel}$ case [if $K_{\parallel} \neq 0$, the right-hand side of Eq. (4) is $\approx 10^3 \text{ eV} \gg \omega_D$]. Using Eqs. (2) and (4), we obtain easily the probability of phonon emission in an angle $d\Omega_k$:

$$\begin{aligned} \frac{dw}{d\Omega_k} &= N \sum_{\mathbf{K}_{\perp}} \exp(-\bar{Z}) V_{\mathbf{f}_{\mathbf{k}} + \mathbf{K}_{\perp}}^2 \frac{(\mathbf{f}_{\mathbf{k}} + \mathbf{K}_{\perp}, \mathbf{e})^2}{2M} \\ &\times \frac{|\langle n' | e^{i(f_{k\perp} + K_{\perp})x} | n \rangle|^2}{\epsilon_{nn'} + f_{k\parallel}} (\bar{n}_k + 1). \end{aligned} \quad (5)$$

It is clear from this expression that for $\Delta \epsilon_{nn'} > 0$ the phonon emission is mainly along the direction $\theta \sim \pi$ and the phonon frequency is $\omega_k \sim \Delta \epsilon_{nn'} v_s$, where v_s is the velocity of sound; these phonons have the transverse polarization.

If $\Delta \epsilon_{nn'} < 0$ (transition to an upper level), the intensity maximum corresponds to $\theta \sim 0$, and the phonon

*Sov. Phys. Solid State, 1978, Vol. 20, No.10, pp. 1807-1808.

frequency is then $\omega_k \sim -\Delta \epsilon_{nn'} v_s$. In the Cherenkov emission case ($\Delta \epsilon_{nn'} = 0$) the direction is given by $\theta \sim \pi/2 - v_s$. The first two cases can be used to determine the energy of a particle, because $\Delta \epsilon_{nn'} = f(E)$.

Moreover, this feature can be used for the stimulated generation of phonons with large wave vectors and of frequency w_D . This can be done by establishing an inverted population of the particles in the channel

$$\Delta N = j S \frac{l}{v} (a_n^2 - a_{n'}^2), \quad (6)$$

where j is the density of the current, S is the beam cross section, l is the thickness of the crystal, v is the particle velocity, and a is the coefficient of matching of a plane wave outside a crystal with the wave functions of the particle inside the crystal. The threshold population inversion should satisfy the following simple condition [4]

$$\Delta N_{th} = \frac{\rho}{\tau_c w_{nn'}}, \quad (7)$$

where $w_{n'n}$ is the probability of a transition of a particle from a state n to a state n' , τ_c is the phonon lifetime in

the crystal, and ρ is the number of different of vibration modes in a phonon spectral line. The threshold current density is obtained from Eqs. (6) and (7):

$$j_{th} = \frac{\rho}{\tau_c w_{nn'}} \frac{v}{l S (a_n^2 - a_{n'}^2)}. \quad (8)$$

For the parameters $E = 100 \text{ MeV}$, $\tau_c = 10^{-9} \text{ sec}$, $S = 1 \text{ mm}^2$, $l = 1 \mu$, $a_n^2 - a_{n'}^2 = 10^{-3}$, and $\rho = 10^6$, we find that $j_{th} = 10^{18} \text{ particles} \cdot \text{cm}^{-2} \cdot \text{sec}^{-1}$.

The author is grateful to N. P. Kalashnikov and M. N. Strikhanov for a discussion of the results obtained.

-
- [1] Collection: *Physics of High-Energy Phonons [Russian translation]*, Mir, Moscow (1976), p. 5.
 - [2] M. A. Kumakhov, *JETP*, **45**, 781 (1977).
 - [3] N. P. Kalashnikov and M. N. Strikhanov, *JETP*, **42**, 641 (1975).
 - [4] G. Birnbaum, *Optical Laser s, Suppl. 2 to Adv. Electron. Electron Phys.*, , Academic Press, New York (1964).